

# 1ch Ultra Small High Side Load Switch

## BUS1DJC0GWZ BUS1DJC3GWZ

#### **General Description**

BUS1DJC0GWZ and BUS1DJC3GWZ are low ON-Resistance high-side power switch P-channel MOSFETs. It comes in ultra-small package for portable digital applications. This switch IC operates on low input voltages ranging from 1.1V to 5.0V and exhibits a typical ON-resistance of 63 m $\Omega$  at 3.3V. The turn ON time of the device can be controlled to avoid inrush current.

#### **Features**

- P-MOSFET high-side load switch
- Low input voltage
- Ultra low bias current
- Ultra low standby current
- Built-in discharge circuit
- Built-in soft start circuit
- Built-in short circuit protection
- Input logic : Active-High
- Ultra small package
- ESD protection

## **Applications**

- Digital cameras
- Mobile phones
- Smart phones
- Portable devices
- Digital video cameras

## **Key Specifications**

Input Voltage Range: 1.1V to 5.0V R<sub>ON</sub> (at V<sub>IN</sub>=1.2V): 140m $\Omega$  (Typ) R<sub>ON</sub> (at V<sub>IN</sub>=3.3V): 63m $\Omega$  (Typ) Bias Current: 0.35 $\mu$ A(Typ) Standby Current: 0.01 $\mu$ A (Typ) Operating Temperature Range: -30°C to +85°C

Package UCSP30L1 W(Typ) x D(Typ) x H(Max) 0.8mm x 0.8mm x 0.35mm

## **Typical Application Circuits**

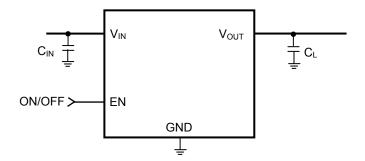


Figure 1. Typical Application Circuits

## **Pin Configurations**

В	EN	GND	В			$\bigcirc$
Α	V <sub>IN</sub>	V <sub>OUT</sub>	А			$\bigcirc$
	Top View			2 1	1	2
				Top View	Botton	n View

Figure 2. Pin Configuration

**Pin Descriptions** 

Seconplions							

## **Block Diagram**

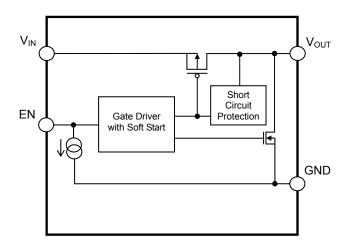


Figure 3. Block Diagram

**Absolute Maximum Ratings** (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Switch Input Voltage	V <sub>IN</sub>	-0.3 to +5.5	V
Switch Output Voltage	V <sub>OUT</sub>	-0.3 to V <sub>IN</sub> +0.3	V
Enable Input Voltage	V <sub>EN</sub>	-0.3 to +5.5	V
Power Dissipation	Pd	0.41 <sup>(Note 1)</sup>	W
Operating Temperature Range	Topr	-30 to +85	°C
Storage Temperature Range	Tstg	-55 to +125	°C
Junction Temperature	Tjmax	125	°C

(Note 1) Derate by 4.1mW/°C when operating above 25°C. (When mounted on a 9 layer glass-epoxy board with 63mm x 55mm x 1.6mm dimension.)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

## **Recommended Operating Conditions** (Ta= -30°C to +85°C)

Parameter	Symbol	Min	Тур	Max	Unit
Switch Input Voltage	V <sub>IN</sub>	1.1	-	5.0	V
Output Current	I <sub>OUT</sub>	-	-	2 (Note 2)	Α

(Note 2) Not to exceed Pd and ASO.

Electrical Characteristics (Unless otherwise specified, V<sub>IN</sub>=3.3V, V<sub>EN</sub>=3.3V, Ta=25°C)

trical Characteristics (Offices Office Specified, VIN-3.3V, VEN-3.3V, 18-23 C)						
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Operating Current	I <sub>IN</sub>	-	0.35	1	μΑ	V <sub>EN</sub> =3.3V, I <sub>OUT</sub> =0A
OFF Supply Current	I <sub>IN_OFF</sub>	-	0.01	1	μA	V <sub>EN</sub> =0V, V <sub>OUT</sub> =OPEN
Leakage Current	I <sub>IN_Leak</sub>	-	0.01	1	μA	V <sub>EN</sub> =0V, V <sub>OUT</sub> =0V
ON-Resistance 1	R <sub>ON1</sub>	-	140	245	mΩ	V <sub>IN</sub> =1.2V
ON-Resistance 2	R <sub>ON2</sub>	-	80	125	mΩ	V <sub>IN</sub> =1.8V
ON-Resistance 3	R <sub>ON3</sub>	-	63	85	mΩ	V <sub>IN</sub> =3.3V
ON-Resistance 4	R <sub>ON4</sub>	-	58	80	mΩ	V <sub>IN</sub> =5.0V
EN High Voltage	V <sub>EN_High</sub>	0.85	-	5.0	V	
EN Low Voltage	V <sub>EN_Low</sub>	-0.3	-	0.4	V	
EN Bias Current	I <sub>EN</sub>	-	0.7	1.5	μA	V <sub>EN</sub> =3.3V
Discharge ON-Resistance	R <sub>ON_DIS</sub>	50	80	110	Ω	V <sub>EN</sub> =0V

## BUS1DJC0GWZ

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-ON Time 1	t <sub>ON1</sub>	-	32	-	µsec	$V_{IN}$ =1.2V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F
Turn-ON Time 2	t <sub>ON2</sub>	-	12	-	µsec	$V_{IN}$ =3.3V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F
Turn-OFF Time	t <sub>OFF</sub>	-	25	-	µsec	$V_{IN}$ =3.3V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F

#### **BUS1DJC3GWZ**

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Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Turn-ON Time 1	t <sub>ON1</sub>	-	510	-	µsec	$V_{IN}$ =1.2V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F	
Turn-ON Time 2	t <sub>ON2</sub>	-	190	-	µsec	$V_{IN}$ =3.3V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F	
Turn-OFF Time	t <sub>OFF</sub>	-	25	-	µsec	$V_{IN}$ =3.3V, $R_L$ =510 $\Omega$ , $C_L$ =0.1 $\mu$ F	

### **Measurement Circuit**

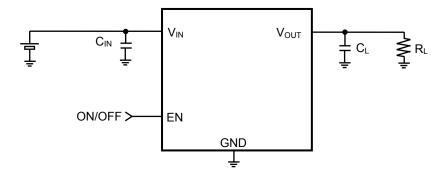


Figure 4. Measurement Circuit

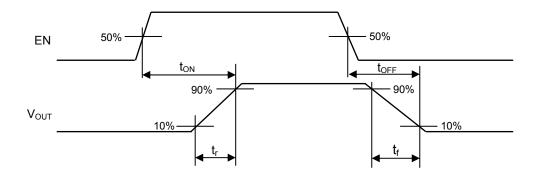


Figure 5. Timing Diagram

## **Typical Performance Curves**

(Unless otherwise specified, Ta=25°C, V<sub>EN</sub>=3.3V, V<sub>IN</sub>=3.3V)

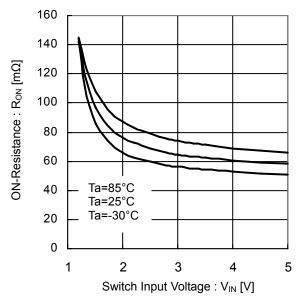


Figure 6. ON-Resistance vs Switch Input Voltage

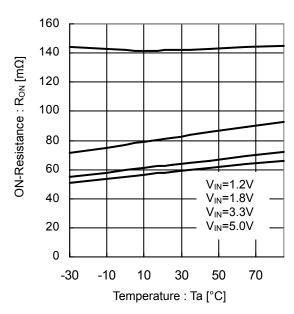


Figure 7. ON-Resistance vs Temperature

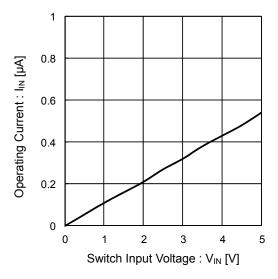


Figure 8. Operating Current vs Switch Input Voltage

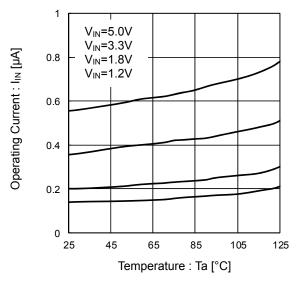


Figure 9. Operating Current vs Temperature

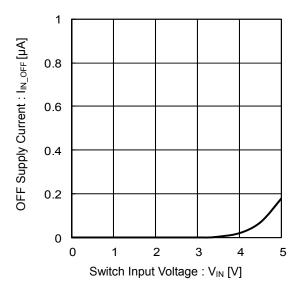


Figure 10. OFF Supply Current vs Switch Input Voltage  $(V_{EN}=0V)$ 

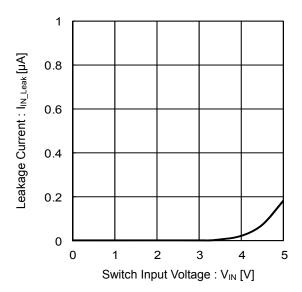


Figure 12. Leakage Current vs Switch Input Voltage  $(V_{EN}=0V, V_{OUT}=0V)$ 

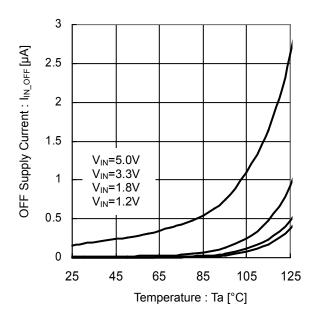


Figure 11. OFF Supply Current vs Temperature  $(V_{EN}=0V)$ 

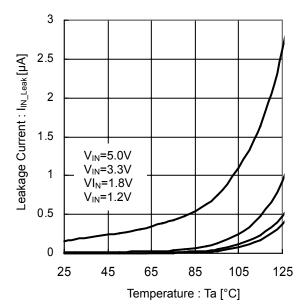


Figure 13. Leakage Current vs Temperature (V<sub>EN</sub>=0V, V<sub>OUT</sub>=0V)

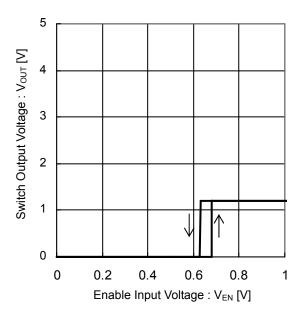


Figure 14. Switch Output Voltage vs Enable Input Voltage  $(V_{IN}=1.2V)$ 

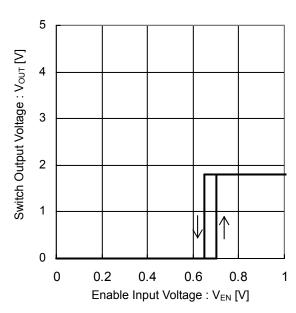


Figure 15. Switch Output Voltage vs Enable Input Voltage  $(V_{IN}=1.8V)$ 

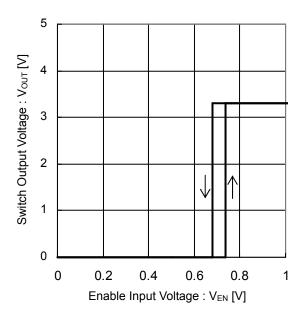


Figure 16. Switch Output Voltage vs Enable Input Voltage  $(V_{IN}=3.3V)$ 

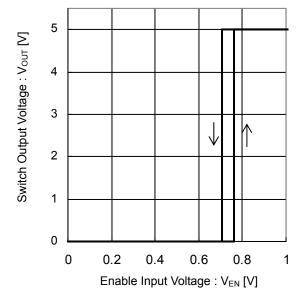


Figure 17. Switch Output Voltage vs Enable Input Voltage  $(V_{IN}=5.0V)$ 

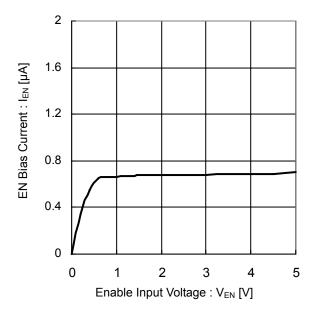


Figure 18. EN Bias Current vs Enable Input Voltage

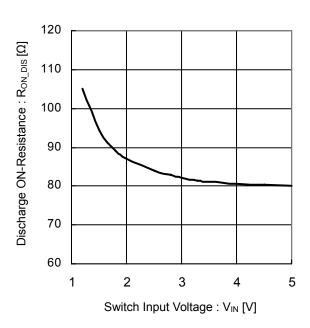


Figure 19. Discharge ON-Resistance vs Switch Input Voltage

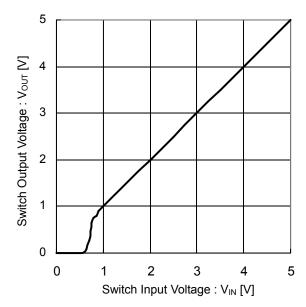


Figure 20. Switch Output Voltage vs Switch Input Voltage (V<sub>EN</sub>=3.3V)

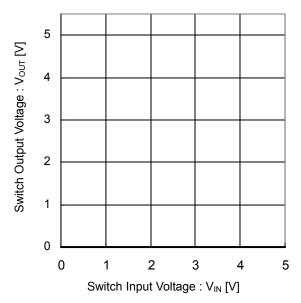


Figure 21. Switch Output Voltage vs Switch Input Voltage  $(V_{EN}=0V)$ 

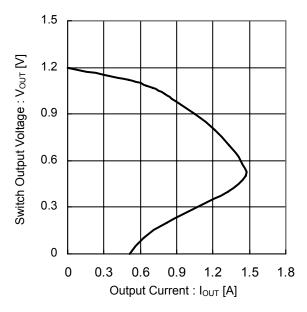


Figure 22. Switch Output Voltage vs Output Current  $(V_{IN}=1.2V)$ 

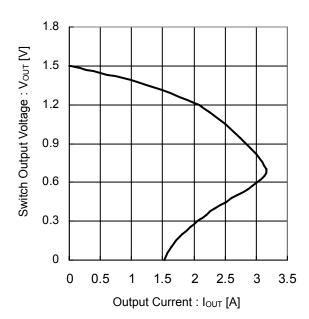


Figure 23. Switch Output Voltage vs Output Current  $(V_{IN}=1.5V)$ 

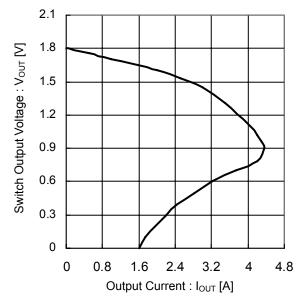


Figure 24. Switch Output Voltage vs Output Current  $(V_{IN}=1.8V)$ 

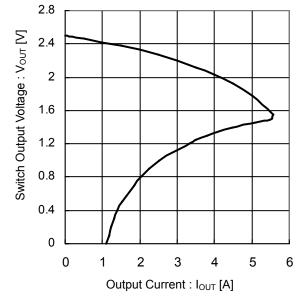


Figure 25. Switch Output Voltage vs Output Current  $(V_{IN}=2.5V)$ 

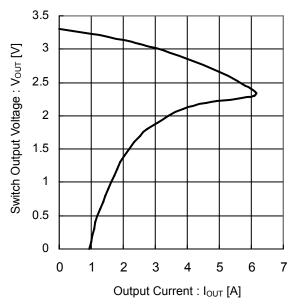


Figure 26. Switch Output Voltage vs Output Current  $(V_{IN}=3.3V)$ 

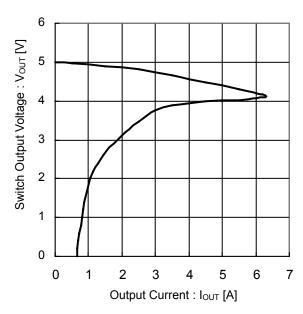


Figure 27. Switch Output Voltage vs Output Current (V<sub>IN</sub>=5.0V)

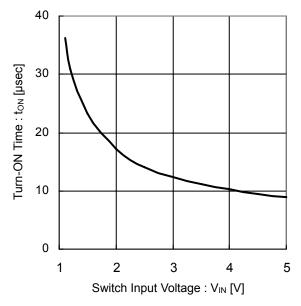


Figure 28. Turn-ON Time vs Switch Input Voltage (BUS1DJC0GWZ)

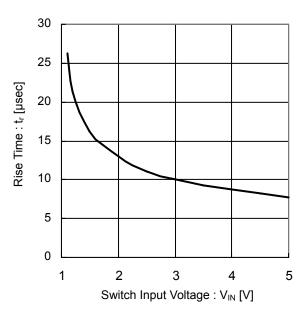


Figure 29. Rise Time vs Switch Input Voltage (BUS1DJC0GWZ)

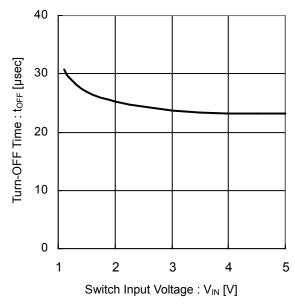


Figure 30. Turn-OFF Time vs Switch Input Voltage (BUS1DJC0GWZ)

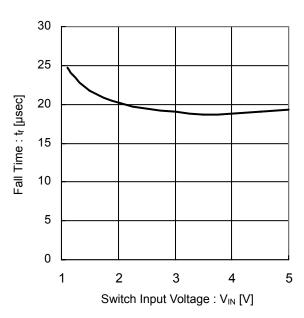


Figure 31. Fall Time vs Switch Input Voltage (BUS1DJC0GWZ)

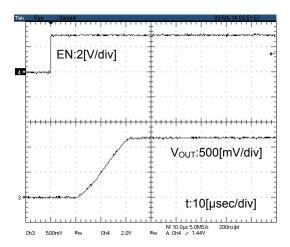


Figure 32. Turn ON Response 1 (BUS1DJC0GWZ V<sub>IN</sub>=1.2V)

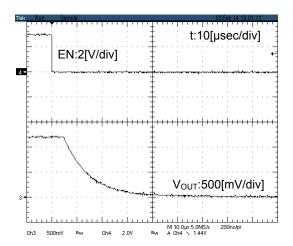


Figure 33. Turn OFF Response 1 (BUS1DJC0GWZ  $V_{IN}$ =1.2V)

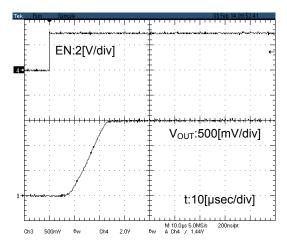


Figure 34. Turn ON Response 2 (BUS1DJC0GWZ  $V_{IN}$ =1.5V)

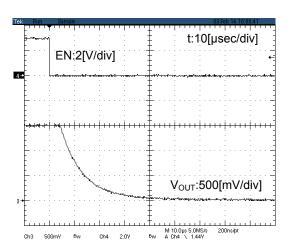


Figure 35. Turn OFF Response 2 (BUS1DJC0GWZ V<sub>IN</sub>=1.5V)

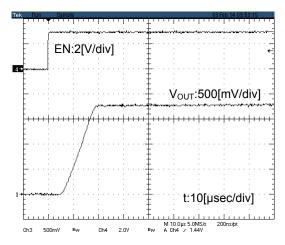
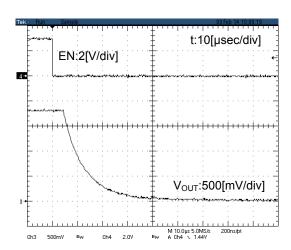


Figure 36. Turn ON Response 3 (BUS1DJC0GWZ  $V_{IN}$ =1.8V)



 $\begin{array}{ll} \text{Figure 37. Turn OFF Response 3} \\ \text{(BUS1DJC0GWZ} & V_{\text{IN}}\text{=}1.8\text{V}) \end{array}$ 

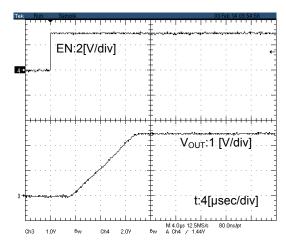


Figure 38. Turn ON Response 4 (BUS1DJC0GWZ  $V_{IN}$ =2.5V)

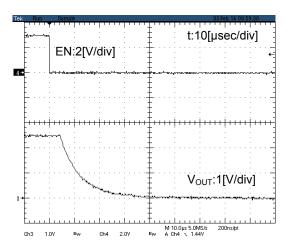
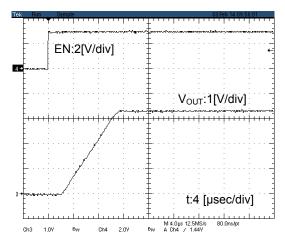
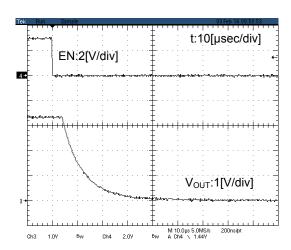


Figure 39. Turn OFF Response 4 (BUS1DJC0GWZ  $V_{IN}$ =2.5V)



 $\begin{array}{ll} \mbox{Figure 40. Turn ON Response 5} \\ \mbox{(BUS1DJC0GWZ} & \mbox{V}_{\mbox{IN}} \mbox{=} 3.3\mbox{V} ) \end{array}$ 



 $\begin{array}{ll} \text{Figure 41. Turn OFF Response 5} \\ \text{(BUS1DJC0GWZ} & V_{\text{IN}}\text{=}3.3V) \end{array}$ 

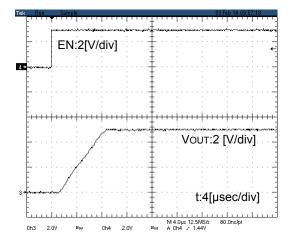


Figure.42 Turn on response 6 (BUS1DJC0GWZ VIN=5.0V)

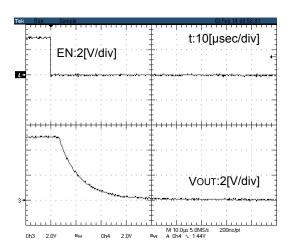


Figure.43 Turn off response 6 (BUS1DJC0GWZ VIN=5.0V)

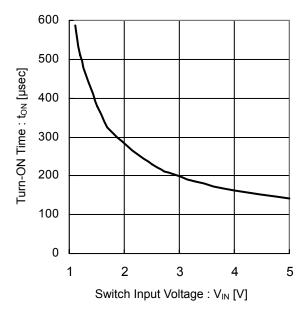


Figure 44. Turn-ON Time vs Switch Input Voltage (BUS1DJC3GWZ)

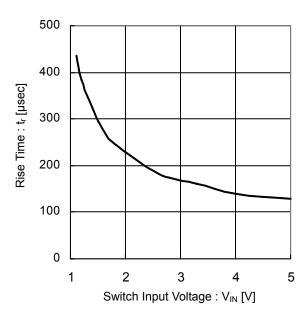


Figure 45. Rise Time vs Switch Input Voltage (BUS1DJC3GWZ)

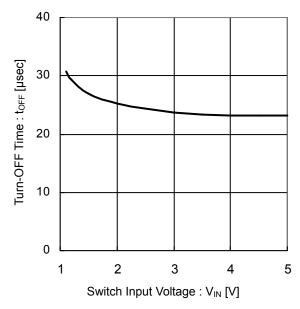


Figure 46. Turn-OFF Time vs Switch Input Voltage (BUS1DJC3GWZ)

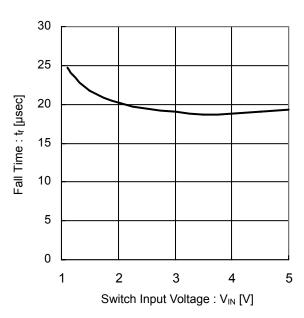


Figure 47. Fall Time vs Switch Input Voltage (BUS1DJC3GWZ)

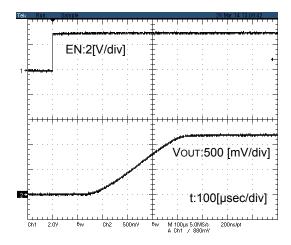


Figure.48 Turn on response 7 (BUS1DJC3GWZ VIN=1.2V)

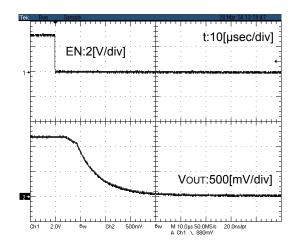


Figure.49 Turn off response 7 (BUS1DJC3GWZ VIN=1.2V)

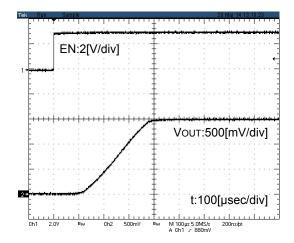


Figure.50 Turn on response 8 (BUS1DJC3GWZ VIN=1.5V)

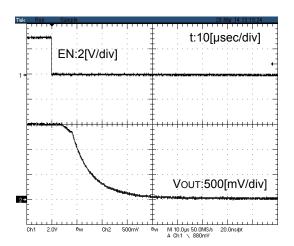


Figure.51 Turn off response 8 (BUS1DJC3GWZ VIN=1.5V)

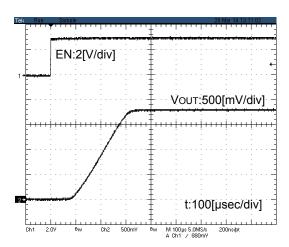


Figure.52 Turn on response 9 (BUS1DJC3GWZ VIN=1.8V)

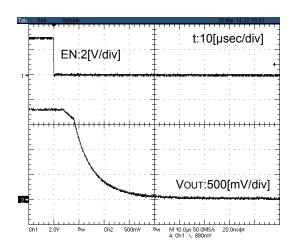


Figure.53 Turn off response 9 (BUS1DJC3GWZ VIN=1.8V)

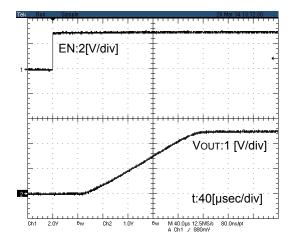


Figure.54 Turn on response 10 (BUS1DJC3GWZ VIN=2.5V)

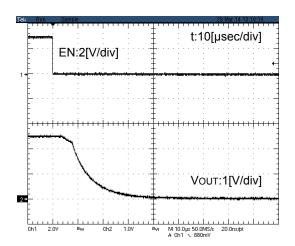


Figure.55 Turn off response 10 (BUS1DJC3GWZ VIN=2.5V)

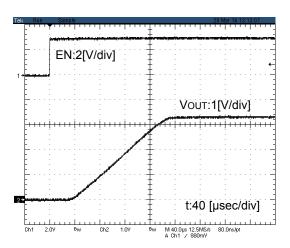


Figure.56 Turn on response 11 (BUS1DJC3GWZ VIN=3.3V)

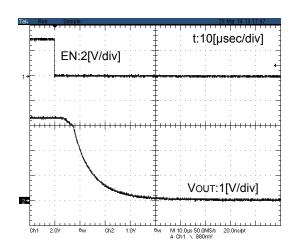


Figure.57 Turn off response 11 (BUS1DJC3GWZ VIN=3.3V)

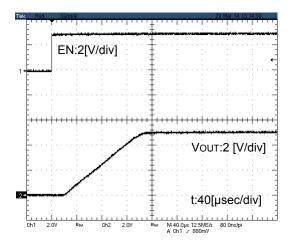


Figure.58 Turn on response 12 (BUS1DJC3GWZ Vin=5V)

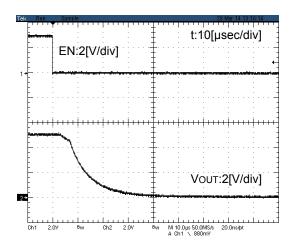


Figure.59 Turn off response 12 (BUS1DJC3GWZ Vin=5V)

#### **Application Information**

It is recommended that an input bypass/decoupling capacitor (over  $0.1\mu F$ ) is placed near the IC between the  $V_{IN}$  and GND pins. The capacitor between  $V_{IN}$  and GND pins is necessary when there is high impedance on the power supply or if the power trace is long. Larger capacitance value  $(0.1\mu F$  to  $100\mu F)$  would result to better line regulation and will improve power characteristics during load change. However, IC operation must be confirmed by mounting the device on an actual application board.

### **Power Dissipation**

An estimation of heat reduction characteristics and internal power consumption of the IC are shown below. Use these for reference. It is recommended to measure Pd on a set board since power dissipation changes substantially according to the implementation conditions (board size, board thickness, metal wiring rate, number of layers and through holes, etc.). Exceeding the power dissipation of IC may lead to degradation of the original IC performance, such as reduction in current capability of the device. It is recommended to provide sufficient margin within the power dissipation rating for usage.

Calculation of the internal power consumption of IC (P)

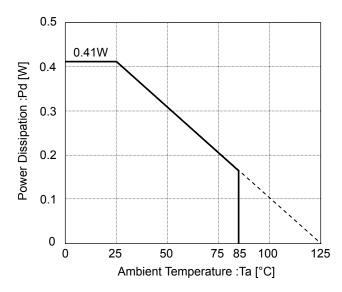
$$P = R_{ON} \times I_{OUT} \times I_{OUT}$$

Where

 $R_{\text{ON}}$  is the ON-state resistance  $I_{\text{OUT}}$  is the Average output current

#### Measurement Conditions

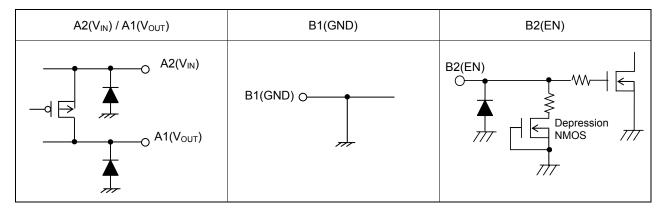
		Evalua	ation Board					
Layout of I Measurem		Top Layer (Top View)	Bottom Layer (Top View)					
Measur	ement State	With board implement	red (Wind speed 0 m/s)					
Boar	d Material	Glass epo	xy resin (9 layers)					
Boa	ard Size	63 mm x 55 mm x 1.6 mm						
Wiring	Top layer	Metal (GND) wiring rate: Approx. 0%						
Rate Bottom layer		Metal (GND) wiring rate: Approx. 50%						
Through Hole		Diameter 0.5mm x 6 holes						
Pov	ver Dissipation	0.4	11W					
	ermal sistance	θja=243.9°C/W						



\* Please design the margin so that P is less than Pd (P < Pd) within the usage temperature range

Figure 60. UCSP30L1(BUS1DJC0GWZ/ BUS1DJC3GWZ) Power Dissipation Heat Reduction Characteristics (Reference)

## I/O Equivalence Circuits



#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned OFF completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

## 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## Operational Notes - continued

#### 11. Unused Input Terminals

Input terminals of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input terminals should be connected to the power supply or ground line.

#### 12. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

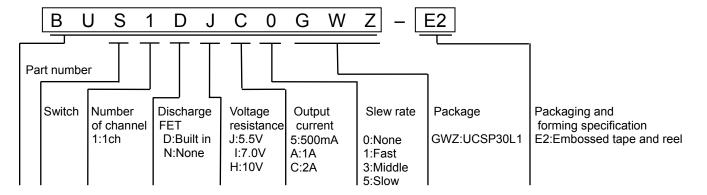
#### 13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

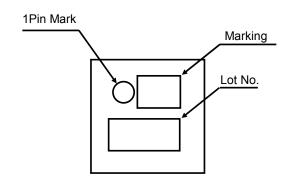
#### 14. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

## **Ordering Information**



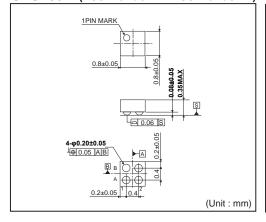
### **Marking Diagram**

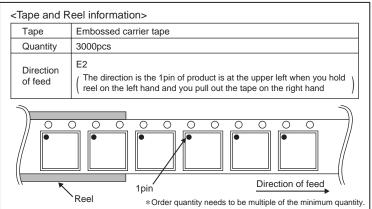


Part No.	Marking
BUS1DJC0GWZ	GV
BUS1DJC3GWZ	GX

## **Physical Dimension, Tape and Reel Information**

## UCSP30L1(BUS1DJC0GWZ / BUS1DJC3GWZ)





## **Revision History**

Date	Revision	Changes
11.Mar.2014	001	New Release
8.Apr.2014	002	Added BUS1DJC3GWZ

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